Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:
Ceramic and metal
Overall Length:
0.092 inches
Overall Diameter:
0.120 inches
Mounting Method:
Press fit
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
70.0 reverse voltage, peak
Current Rating Per Characteristic:
10.00 microamperes forward current, average major
Power Rating Per Characteristic:
400.0 milliwatts small-signal input power, common-collector preset
Maximum Operating Tempurature Per Measurement Point:
150.0 degrees celsius ambient air
Precious Material And Location:
Terminal surface gold
Precious Material:
Gold
Terminal Type And Quantity:
2 ribbon
Shelf Life:
N/a
Unit Of Measure:
-
Demilitarization:
No
Fiig:
A110a0